STTA806D/DI/G

TURBOSWITCH ULTRA-FAST HIGH VOLTAGE DIODE

MAIN PRODUCTS CHARACTERISTICS

$I_{F(AV)}$	8A
V_{RRM}	600V
t_{rr} (typ)	25ns
V_F (max)	1.5V

FEATURES AND BENEFITS

- SPECIFIC TO "FREEWHEEL MODE" OPERATIONS: FREEWHEEL OR BOOSTER DIODE
- ULTRA-FAST AND SOFT RECOVERY
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR
- HIGH FREQUENCY OPERATIONS
- INSULATED PACKAGE : TO-220AC
  Electrical insulation : 2500V_{RMS}
  Capacitance < 7 pF

**TO-220AC
STTA806D**

**Insulated
TO-220AC
STTA806DI**

**D^{2}PAK
STTA806G**
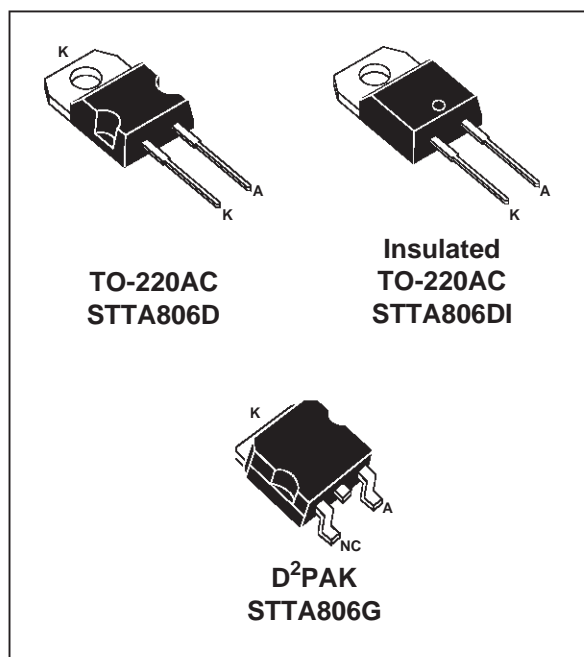
DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V.
TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all "freewheel mode" operations and is particularly suitable and efficient in motor control freewheel applications and in booster diode applications in power factor control circuitries.
Packaged either in TO-220AC, insulated TO-220AC or in D^{2}PAK, these 600V devices are particularly intended for use on 240V domestic mains.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		600	V
V_{RSM}	Non repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	RMS forward current	TO-220AC / D^{2}PAK	30	A
		TO-220AC ins.	20	A
I_{FRM}	Repetitive peak forward current	tp=5ms F=5kHz square	110	A
I_{FSM}	Surge non repetitive forward current	tp=10 ms sinusoidal	90	A
T_j	Maximum operating junction temperature		150	°C
T_{stg}	Storage temperature range		-65 to 150	°C

TM : TURBOSWITCH is a trademark of STMicroelectronics

THERMAL AND POWER DATA

Symbol	Parameter		Conditions	Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance	TO-220AC / D^{2}PAK TO-220AC ins.		2.2 3.3	°C/W
P_1	Conduction power dissipation $I_{F(AV)} = 8A \quad \delta = 0.5$	TO-220AC / D^{2}PAK TO-220AC ins.	Tc= 118°C Tc= 102°C	14.5	W
P_{max}	Total power dissipation Pmax = P1 + P3 (P3 = 10% P1)	TO-220AC /D^{2}PAK TO-220AC ins.	Tc= 115°C Tc= 97°C	16	W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Min	Typ	Max	Unit
V_F *	Forward voltage drop	$I_F = 8A$	Tj = 25°C Tj = 125°C		 1.25	1.75 1.5	V V
I_R **	Reverse leakage current	$V_R = 0.8 \times V_{RRM}$	Tj = 25°C Tj = 125°C		 1.5	100 4	μA mA
V_{to}	Threshold voltage	$Ip < 3.I_{AV}$	Tj = 125°C			1.15	V
rd	Dynamic resistance					43	mΩ

Test pulse :   * tp = 380 μs, δ < 2%
                ** tp = 5 ms, δ < 2%

To evaluate the maximum conduction losses use the following equation :
$P = V_{to} \times I_{F(AV)} + rd \times I_F^2{}_{(RMS)}$

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{rr}	Reverse recovery time	Tj = 25°C $I_F = 0.5$ A $I_R = 1$A Irr = 0.25A $I_F = 1$ A $dI_F/dt = -50$A/μs $V_R = 30$V		25	 52	ns
I_{RM}	Maximum reverse recovery current	Tj = 125°C VR = 400V $I_F = 8$A $dI_F/dt = -64$ A/μs $dI_F/dt = -500$ A/μs		 14	 5.5	A
S factor	Softness factor	Tj = 125°C $V_R = 400$V $I_F = 8$A $dI_F/dt = -500$ A/μs		 0.47		-

TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	Tj = 25°C $I_F = 8$ A, $dI_F/dt = 64$ A/μs measured at, $1.1 \times V_F$max			 500	ns
V_{Fp}	Peak forward voltage	Tj = 25°C $I_F = 8$A, $dI_F/dt = 64$ A/μs			 10	V

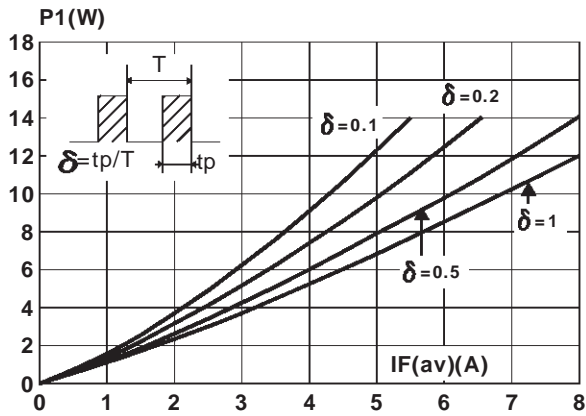**Fig. 1:** Conduction losses versus average current.

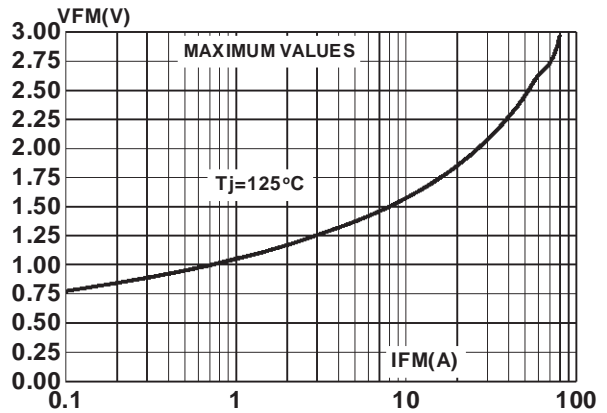**Fig. 2:** Forward voltage drop versus forward current.

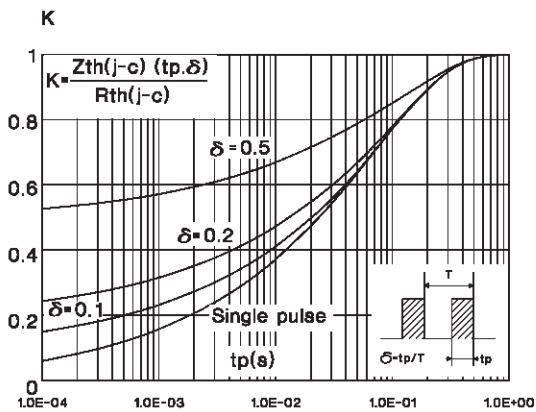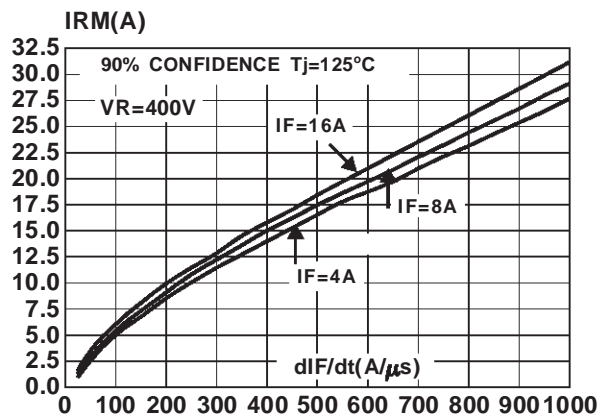**Fig. 3:** Relative variation of thermal transient impedance junction to case versus pulse duration.
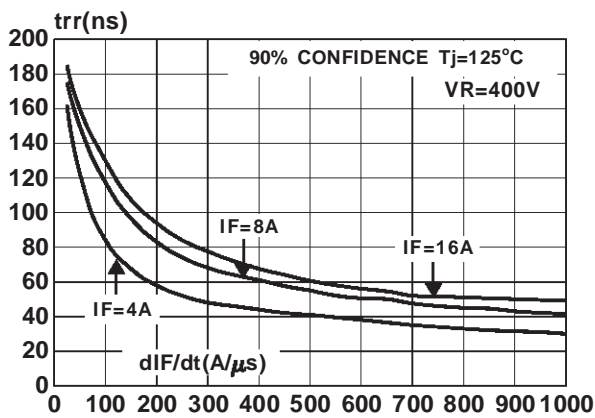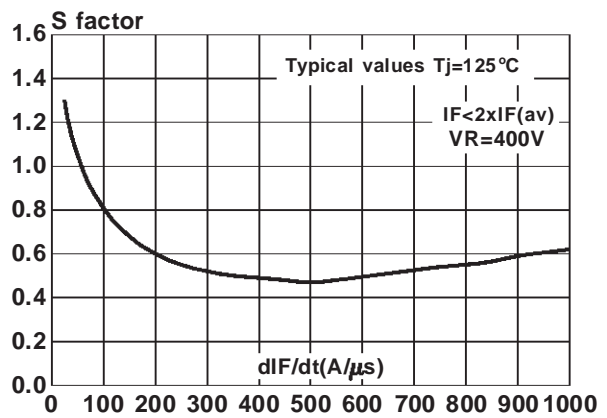

Fig. 4: Peak reverse recovery current versus dI_F/dt.

Fig. 5: Reverse recovery time versus dI_F/dt.

Fig. 6: Softness factor (tb/ta) versus dI_F/dt.

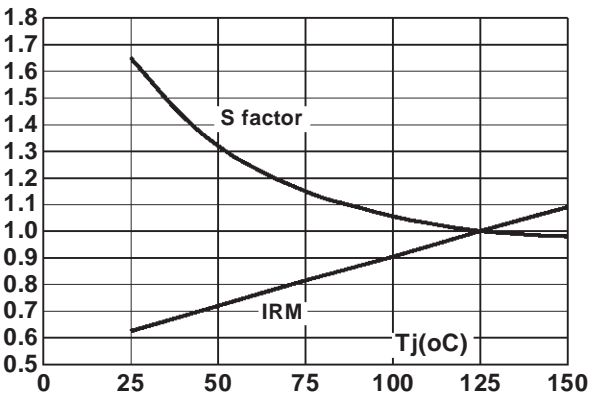**Fig. 7:** Relative variation of dynamic parameters versus junction temperature (reference Tj=125°C).

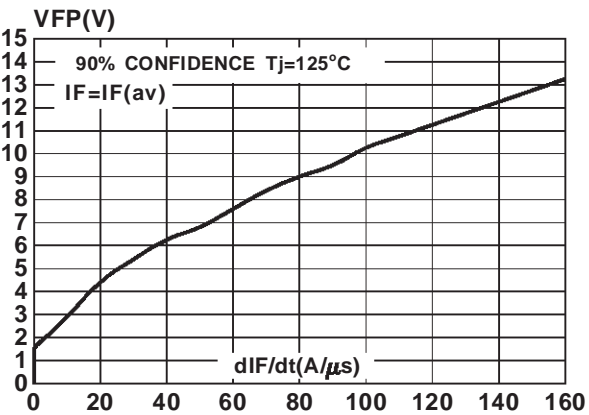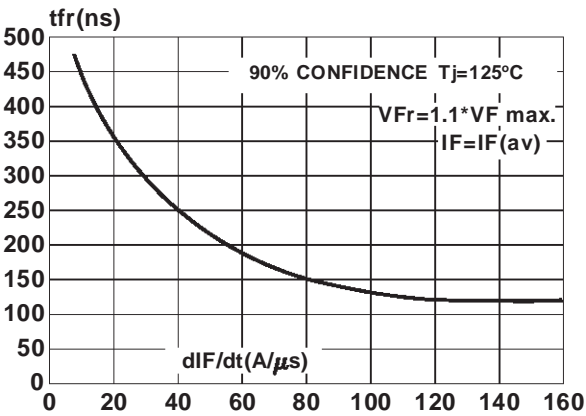**Fig. 8:** Transient peak forward voltage versus dIF/dt.

Fig. 9: Forward recovery time versus dIF/dt.

APPLICATION DATA

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion transistor, thus optimizing the overall performance in the end application.

The way of calculating the power losses is given below:

TOTAL LOSSES
due to the diode

$$P = P1 + P2 + P3 + P4 + P5 \quad \text{Watts}$$

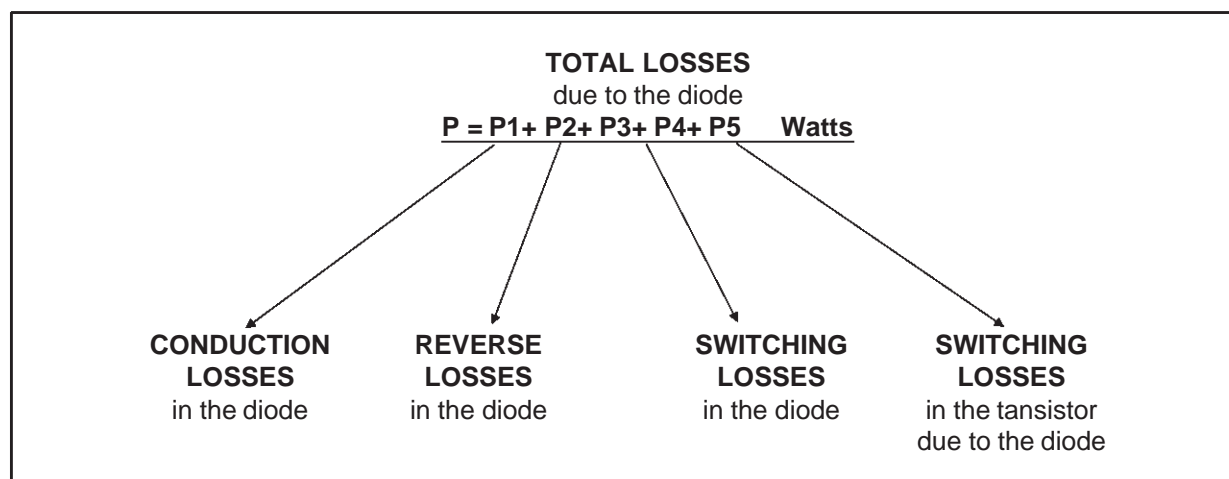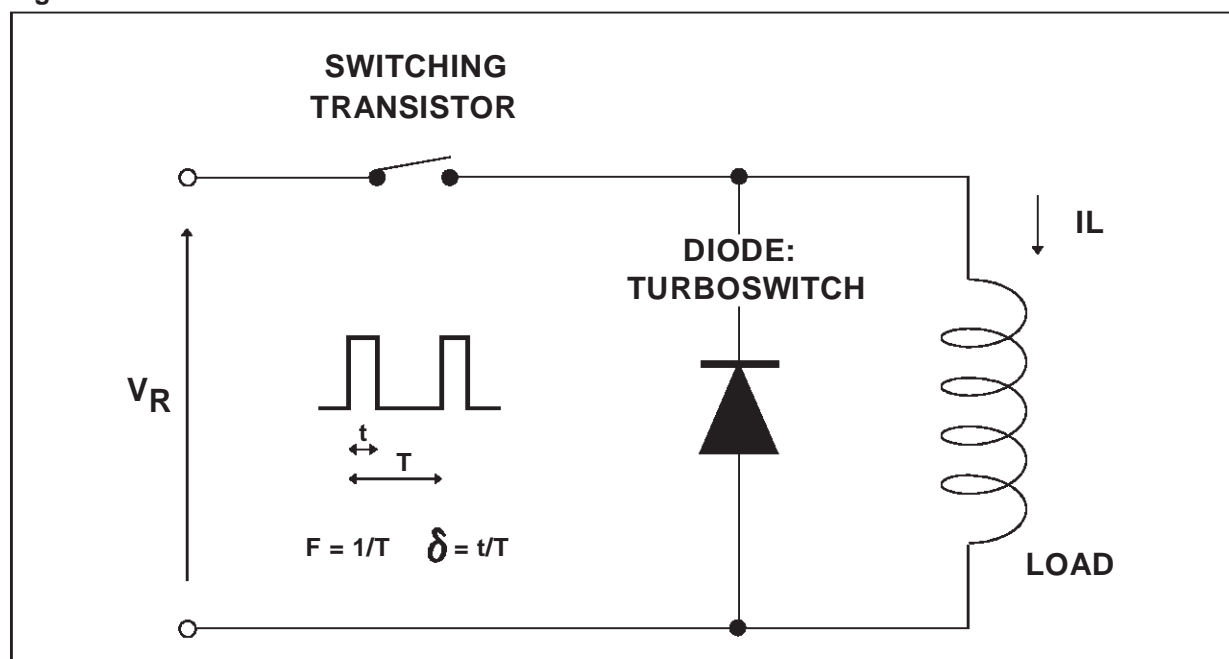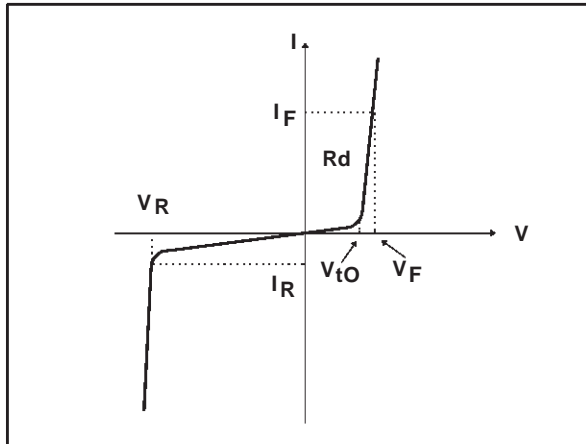| **CONDUCTION LOSSES** in the diode | **REVERSE LOSSES** in the diode | **SWITCHING LOSSES** in the diode | **SWITCHING LOSSES** in the tansistor due to the diode |

Fig. A : "FREEWHEEL" MODE.

APPLICATION DATA (Cont'd)
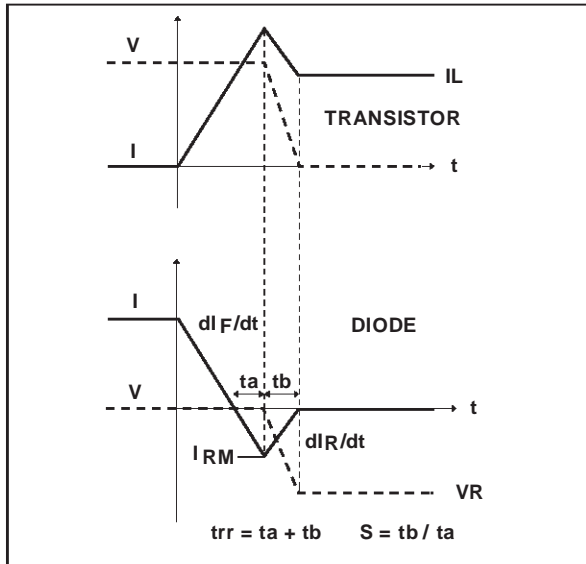
Fig. B: STATIC CHARACTERISTICS

Conduction losses :

$P1 = V_{t0} \cdot I_{F(AV)} + R_d \cdot I_F^2(RMS)$

Reverse losses :

$P2 = V_R \cdot I_R \cdot (1 - \delta)$

Fig. C: TURN-OFF CHARACTERISTICS

Turn-on losses :
(in the transistor, due to the diode)

$$P5 = \frac{V_R \times I_{RM^2} \times (3 + 2 \times S) \times F}{6 \ x \ dI_F / dt}$$
$$+ \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \ x \ dI_F / dt}$$

Turn-off losses (in the diode) :

$$P3 = \frac{V_R \times I_{RM^2} \times S \times F}{6 \ x \ dI_F / dt}$$

P3 and P5 are suitable for power MOSFET and IGBT

Fig. D: TURN-ON CHARACTERISTICS
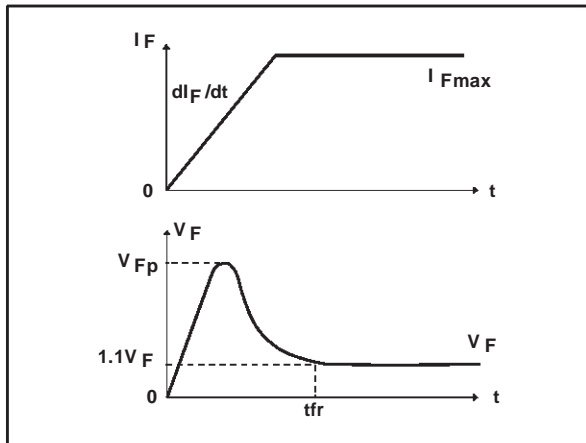
Turn-on losses :
$P4 = 0.4 \ (V_{FP} - V_F) \cdot I_{Fmax} \cdot t_{fr} \cdot F$

PACKAGE DATA
D²PAK

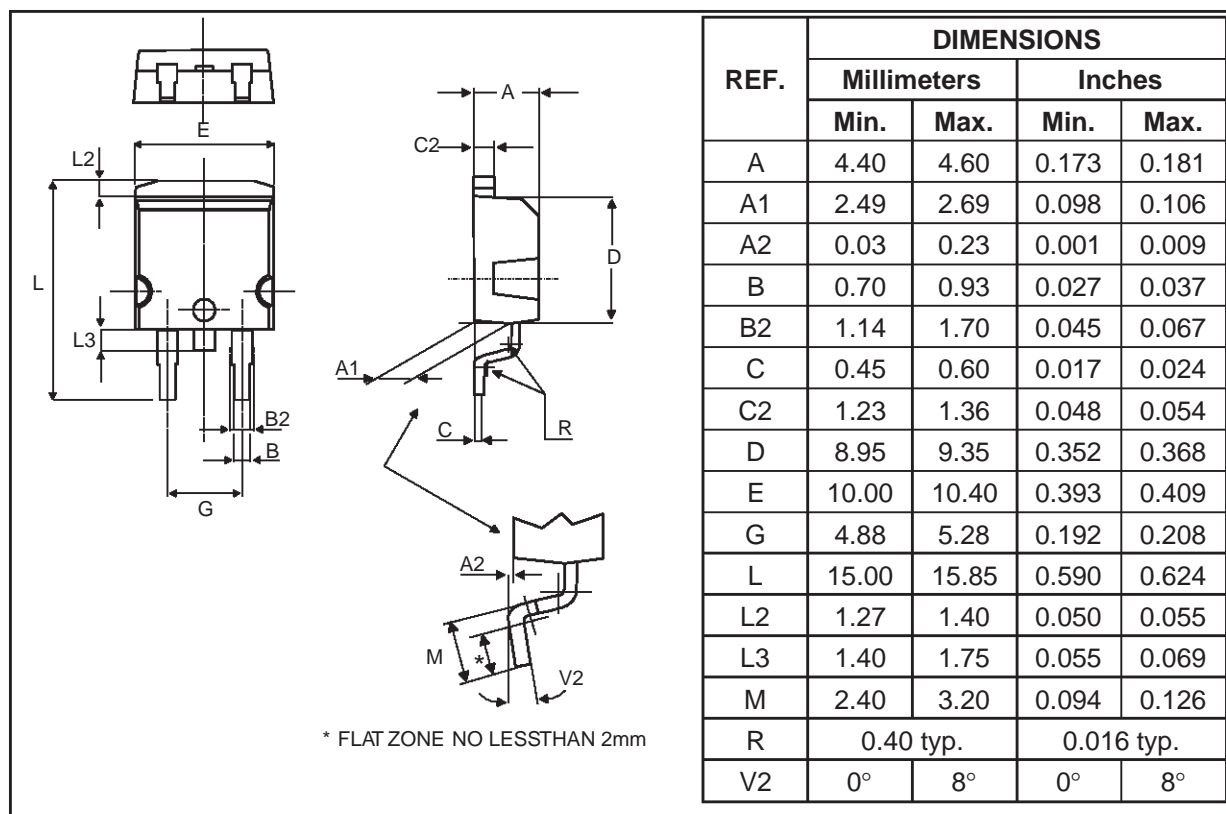| REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

* FLAT ZONE NO LESS THAN 2mm

FOOTPRINT DIMENSIONS (in millimeters)   ▪ Cooling method : by conduction (C)
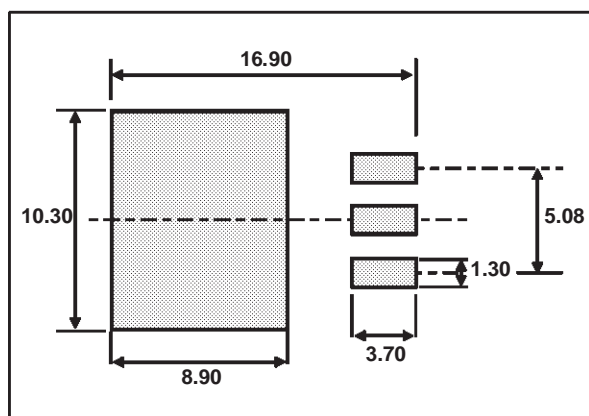
PACKAGE DATA
TO-220AC (JEDEC OUTLINE)

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
H2	10.00	10.40	0.393	0.409
L2	16.40 typ.		0.645 typ.	
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam. I	3.75	3.85	0.147	0.151
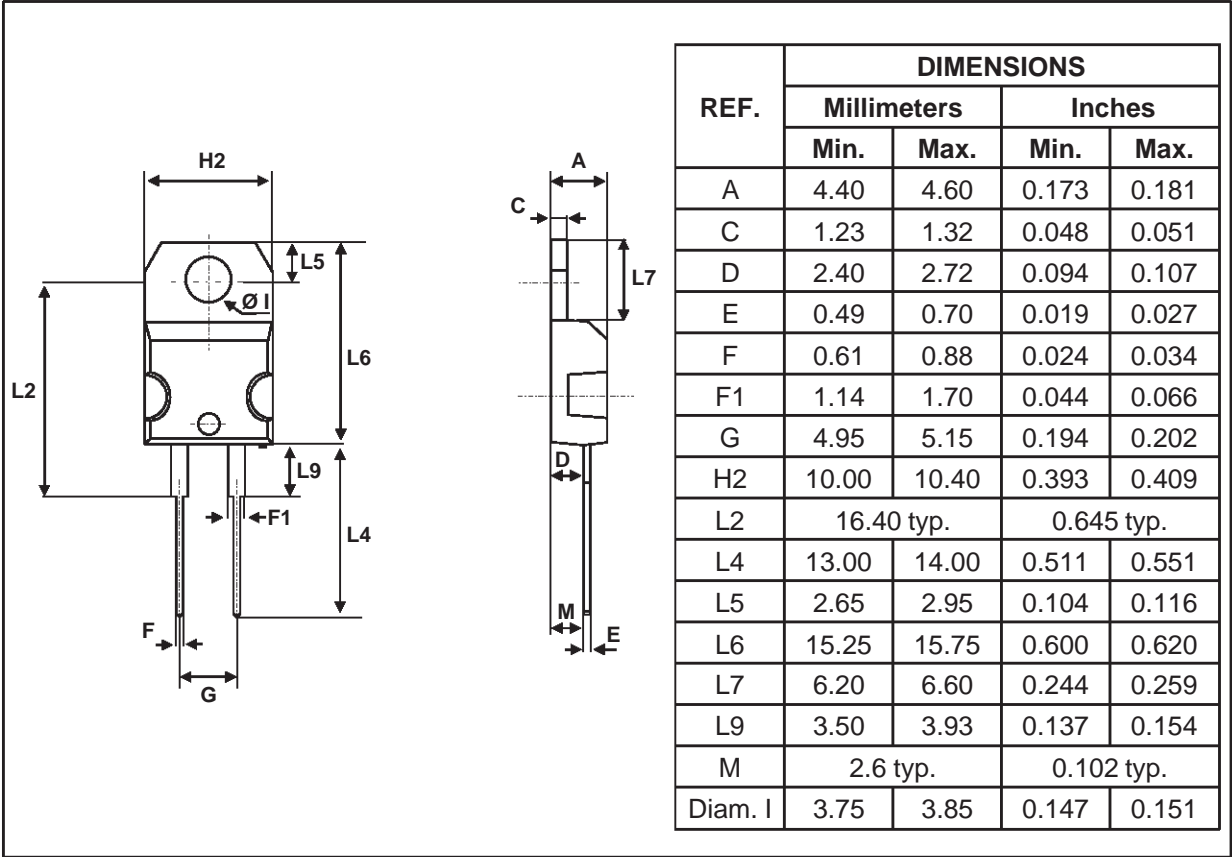
▪ Cooling method : by conduction (C)
▪ Recommanded torque value : 0.55m.N
▪ Maximum torque value : 0.7m.N

PACKAGE DATA
INSULATED TO-220AC

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	4.80		5.40	0.189		0.212
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
l2	1.14		1.70	0.044		0.066
M		2.60			0.102	
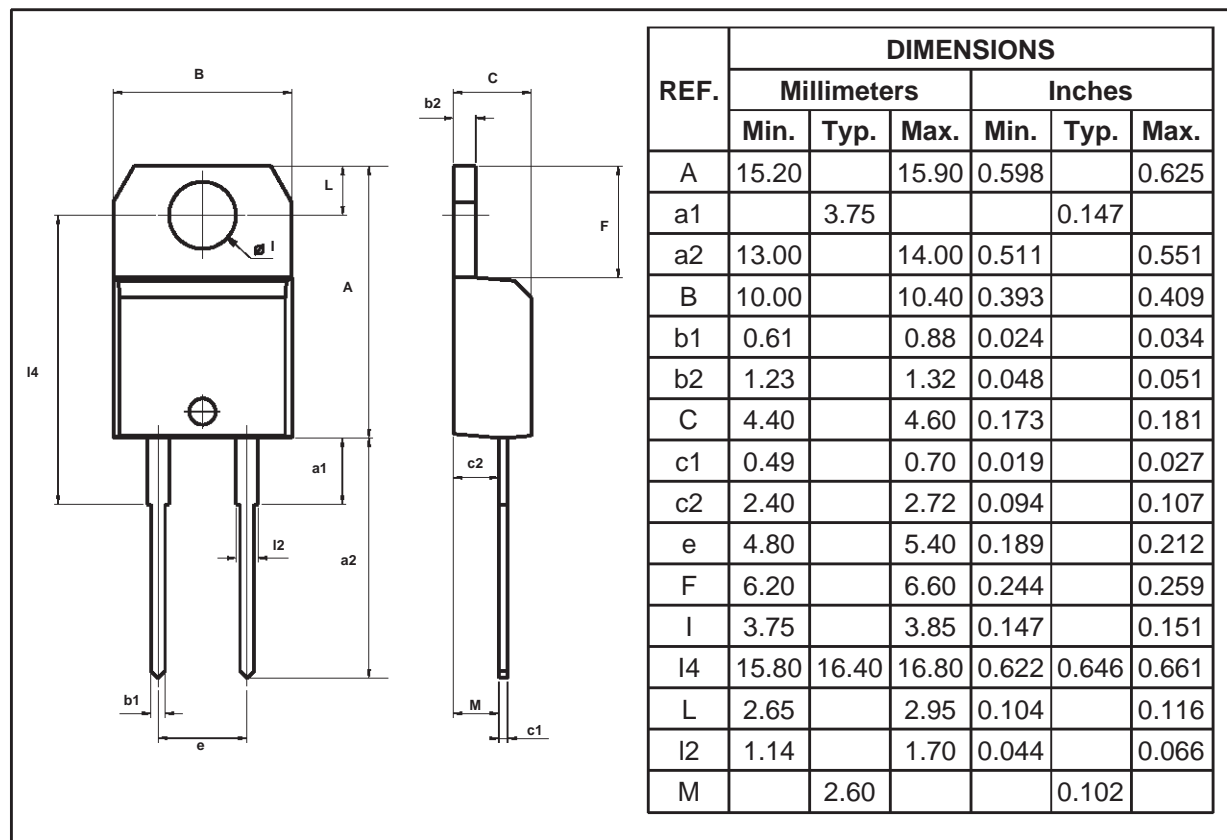
- Cooling method : by conduction (C)
- Recommanded torque value : 0.8m.N
- Maximum torque value : 1m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA806D	STTA806D	TO-220AC	1.86g	50	Tube
STTA806DI	STTA806DI	TO-220AC Ins.	1.86g	250	Bulk
STTA806G	STTA806G	D^{2}PAK	1.48g	50	Tube
STTA806G-TR	STTA806G	D^{2}PAK	1.48g	500	Tape & reel

- Epoxy meets UL94,V0